NSN 5961-00-001-3279

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-001-3279 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.108 inches and 0.140 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-14 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 repetitive peak reverse voltage **Power Rating Per Characteristic:** 500.0 milliwatts total device dissipation **Capacitance Rating In Picofarads:** 6.8 **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No